NSN 5961-00-088-4764

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View Online at https://aerobasegroup.com/nsn/5961-00-088-4764 **Inclosure Material:** Metal **Overall Length:** 0.520 inches **Overall Diameter:** 1.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-36 **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 10.0 emitter to base voltage, static, collector open and 55.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 6.00 amperes repetitive peak forward current blank and 3.00 amperes base current, rms value of alternation component **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector **Transfer Ratio:** 75.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 2 threaded stud Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.